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I hereby certify that this correspondence is being deposited with the U.S. Postal Service with sufficient postage for First Class Mail, in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the date shown below.

Dated: June 3, 2004

Signature: *[Signature]*

Paul B. Stephens

Docket No.: 30205/37980A  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:  
Seon Y. Cha

Application No.: 10/663,892

Art Unit: 2812

Filed: September 16, 2003

Examiner: J. Jey Tsai

For: Magnetic Random Access Memory Having  
Transistor of Vertical Structure with Writing Line  
Formed on an Upper Portion of the Magnetic  
Tunnel Junction Cell

*Please  
amend  
1/3/05*

**AMENDMENT UNDER 37 CFR §1.312**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

**INTRODUCTORY COMMENTS**

Please amend the above-identified U.S. patent application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Remarks** begin on page 3 of this paper.